CPH3461



Power MOSFET 250V, 6.5Ω , 350mA, Single N-Channel

http://onsemi.com

Features

- On-resistance R_{DS}(on)1=5 Ω (typ)
- 2.5V drive • Halogen free compliance

• Protection diode in

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Value	Unit
Drain to Source Voltage	V _{DSS}		250	V
Gate to Source Voltage	VGSS		±10	V
Drain to Gate Voltage	V _{DGS}		250	V
Gate to Drain Voltage	V _{GDS}		±10	V
Drain Current (DC)	ID		350	mA
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	1.4	Α
Power Dissipation	PD	When mounted on ceramic substrate (900mm ² × 0.8mm)	1.0	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit	
Junction to Ambient	$R_{\theta,JA}$	125	°C/W	
When mounted on ceramic substrate (900mm ² ×0.8mm)	N⊕JA	125	C/ VV	

Electrical Characteristics at Ta = 25°C

Davisantan	Symbol	Conditions	Value			11.7
Parameter			min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	250			٧
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =250V, V _{GS} =0V			1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μА
Gate Threshold Voltage	V _{GS} (th)	V _{DS} =10V, I _D =1mA	0.4		1.3	٧
Forward Transconductance	gFS	V _{DS} =10V, I _D =170mA		1		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =170mA, V _{GS} =4.5V		5	6.5	Ω
	R _{DS} (on)2	I _D =170mA, V _{GS} =2.5V		5.1	7.2	Ω

Continued on next page.

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

CPH3461

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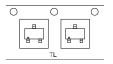
Parameter	0 1 1	0 101	Value			
	Symbol	Conditions	min	typ	max	Unit
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		140		pF
Output Capacitance	Coss			8		pF
Reverse Transfer Capacitance	Crss			3		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		7.5		ns
Rise Time	t _r			7.3		ns
Turn-OFF Delay Time	t _d (off)			23		ns
Fall Time	tf			43		ns
Total Gate Charge	Qg	V _{DS} =125V, V _{GS} =4.5V, I _D =350mA		2.1		nC
Gate to Source Charge	Qgs			0.3		nC
Gate to Drain "Miller" Charge	Qgd			0.7		nC
Forward Diode Voltage	V _{SD}	I _S =350mA, V _{GS} =0V		0.79	1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Ordering & Package Information

Device	Package	Shipping	note
CPH3461-TL-H	CPH3, SC-59 SOT-23, TO-236	3,000 pcs. / reel	Pb-Free and Halogen Free

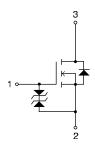
Packing Type:TL



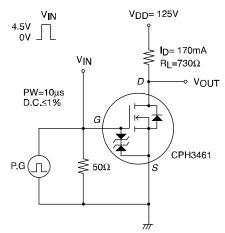
Marking

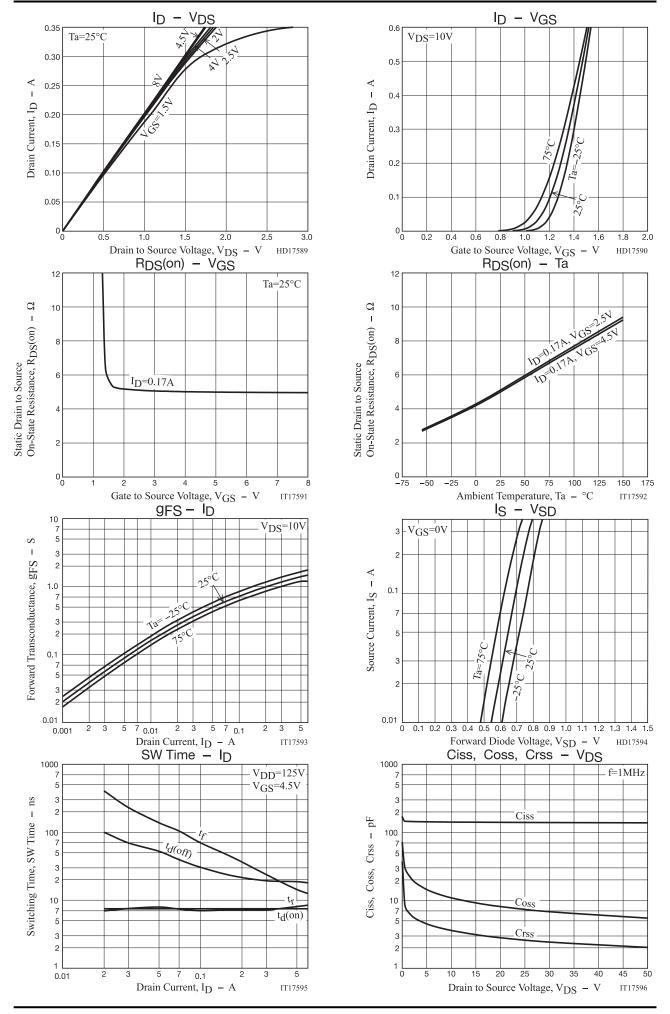


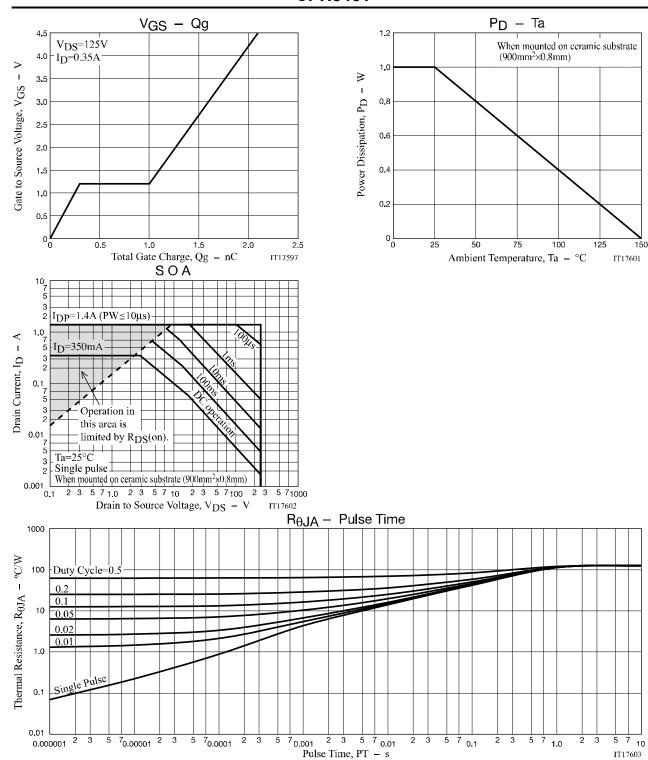
Electrical Connection



Switching Time Test Circuit







Package Dimensions

CPH3461-TL-H

CPH3

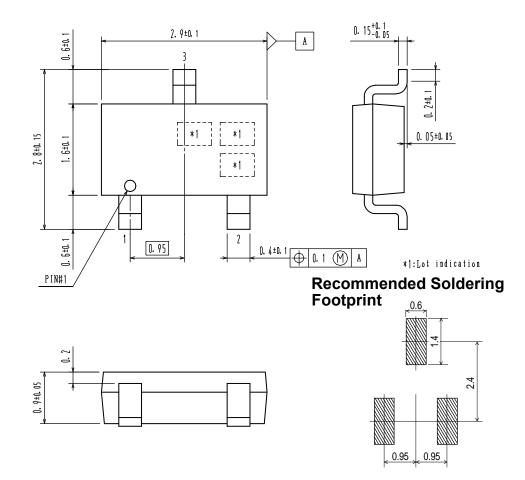
CASE 318BA ISSUE O

unit: mm

1: Gate

2: Source

3: Drain



Note on usage: Since the CPH3461 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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